

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IXTA200N085T

#### • FEATURES

- Static drain-source on-resistance:
  - $R_{DS}(on) \le 5.0 m_{\Omega} @V_{GS}=10V$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION

- DC/DC Converters
- High Current Switching Applications

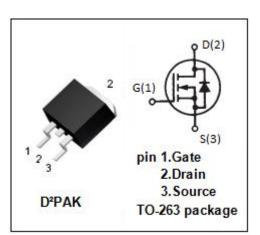
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

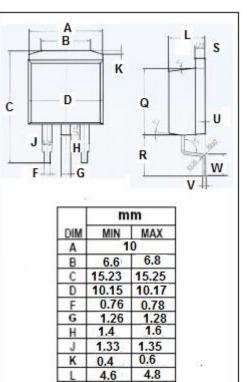
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	85	V			
V <sub>GS</sub>	Gate-Source Voltage	±20	V			
ID	Drain Current-Continuous	200	А			
I <sub>DM</sub>	Drain Current-Single Pulsed	540	А			
PD	Total Dissipation @Tc=25°C	480	W			
Tj	Operating Junction Temperature	-55~175	°C			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.31	°C/W

1





8.69

5.28

1.26

0.0

0.37

2.80

0

R

SU

v

W

8.71

5.30

1.28

0.2

0.39

2.82



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 250 μ A	85		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 250 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		5.0	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±200	nA
	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	μA
I <sub>DSS</sub>		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		250	μΛ
$V_{\text{SD}}$	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.0	V

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